



#### **60V N-CHANNEL ENHANCEMENT MODE MOSFET**

### **Product Summary**

BV <sub>DSS</sub>	R <sub>DS(ON)</sub> Max	I <sub>D</sub> Max T <sub>C</sub> = +25°C
	10mΩ @ V <sub>GS</sub> = 10V	57A
60V	12.8mΩ @ V <sub>GS</sub> = 4.5V	51A

### **Features**

- Low R<sub>DS(ON)</sub> Ensures On State Losses Are Minimized
- Excellent Q<sub>gd x</sub> R<sub>DS(ON)</sub> Product (FOM)
- Advanced Technology for DC/DC Converters
- Small Form Factor Thermally Efficient Package Enables Higher Density End Products
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

# **Description and Applications**

This new generation MOSFET is designed to minimize the on-state resistance ( $R_{DS(ON)}$ ) and yet maintain superior switching performance, making it ideal for high- efficiency power management applications.

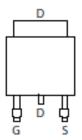
- Power Management Functions
- DC-DC Converters
- Backlighting

### **Mechanical Data**

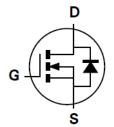
- Case: TO252
- Case Material: Molded Plastic, "Green" Molding Compound.
- UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Finish Matte Tin Annealed over Copper Leadframe;
   Solderable per MIL-STD-202, Method 208 (§3)
- Weight: 0.33 grams (Approximate)



Top View



Pin Out Top View



**Equivalent Circuit** 

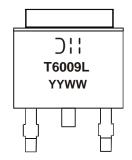
# **Ordering Information** (Note 4)

Part Number	Case	Packaging
DMT6009LK3-13	TO252	2,500/Tape & Reel

Notes:

- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
- 2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

## **Marking Information**



Dil = Manufacturer's Marking
T6009L = Product Type Marking Code
YYWW = Date Code Marking
YY = Last Two Digits of Year (ex: 15 = 2015)
WW = Week Code (01 to 53)



## **Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage	$V_{DSS}$	60	V	
Gate-Source Voltage		$V_{GSS}$	±16	V
Continuous Drain Current (Note 5) V <sub>GS</sub> = 10V	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	I <sub>D</sub>	13.3 10.6	А
Continuous Drain Current (Note 6) $V_{GS} = 10V$ $T_C = +25^{\circ}C$ $T_C = +70^{\circ}C$		I <sub>D</sub>	57 46	А
Maximum Continuous Body Diode Forward Current (Note 6)	Is	80	Α	
Pulsed Drain Current (10μs Pulse, Duty Cycle = 1%)	I <sub>DM</sub>	90	Α	
Avalanche Current, L=0.1mH	I <sub>AS</sub>	20.3	Α	
Avalanche Energy, L=0.1mH	E <sub>AS</sub>	20.6	mJ	

# Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 5)	P <sub>D</sub>	2.6	W
Thermal Resistance, Junction to Ambient (Note 5)	$R_{\theta JA}$	47	°C/W
Total Power Dissipation (Note 6)	P <sub>D</sub>	50	W
Thermal Resistance, Junction to Case (Note 6)	$R_{\theta JC}$	2.5	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	60	-	-	V	$V_{GS} = 0V, I_D = 1mA$	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	-	-	1	μA	V <sub>DS</sub> = 48V, V <sub>GS</sub> = 0V	
Gate-Source Leakage	I <sub>GSS</sub>	-	-	±100	nA	$V_{GS} = \pm 16V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	V <sub>GS(TH)</sub>	0.7	1.4	2	V	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	
Static Drain-Source On-Resistance		-	8.3	10	mΩ	$V_{GS} = 10V, I_D = 13.5A$	
Static Drain-Source On-Resistance	R <sub>DS(ON)</sub>	-	9.6	12.8	mΩ	$V_{GS} = 4.5V, I_D = 11.5A$	
Diode Forward Voltage	V <sub>SD</sub>	-	0.9	1.2	V	$V_{GS} = 0V, I_{S} = 20A$	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	C <sub>iss</sub>	-	1,925	-		V <sub>DS</sub> = 30V, V <sub>GS</sub> = 0V, f = 1MHz	
Output Capacitance	Coss	-	438	-	pF		
Reverse Transfer Capacitance	Crss	-	41	-			
Gate Resistance	Rg	-	1.7	-	Ω	$V_{DS} = 0V$ , $V_{GS} = 0V$ , $f = 1MHz$	
Total Gate Charge (V <sub>GS</sub> = 4.5V)	$Q_g$	-	15.6	-			
Total Gate Charge (V <sub>GS</sub> = 10V)	Qg	-	33.5	-	nC	V 20V I 42.5A	
Gate-Source Charge	Q <sub>gs</sub>	-	4.7	-	nc nc	$V_{DS} = 30V, I_{D} = 13.5A$	
Gate-Drain Charge	$Q_{gd}$	-	5.3	-			
Turn-On Delay Time	t <sub>D(ON)</sub>	-	4.5	-		$V_{DD} = 30V, V_{GS} = 10V,$ $R_G = 6\Omega, I_D = 13.5A$	
Turn-On Rise Time	t <sub>R</sub>	-	8.6	-			
Turn-Off Delay Time	t <sub>D(OFF)</sub>	-	35.9	-	ns		
Turn-Off Fall Time	t <sub>F</sub>	_	15.7	_			
Body Diode Reverse Recovery Time	t <sub>RR</sub>	-	18.2	-	ns	1 42 EA di/dt 400A/::-	
Body Diode Reverse Recovery Charge	$Q_{RR}$	-	33.1	-	nC	$I_F = 13.5A$ , di/dt = 400A/ $\mu$ s	

Notes: 5. Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper pad layout.

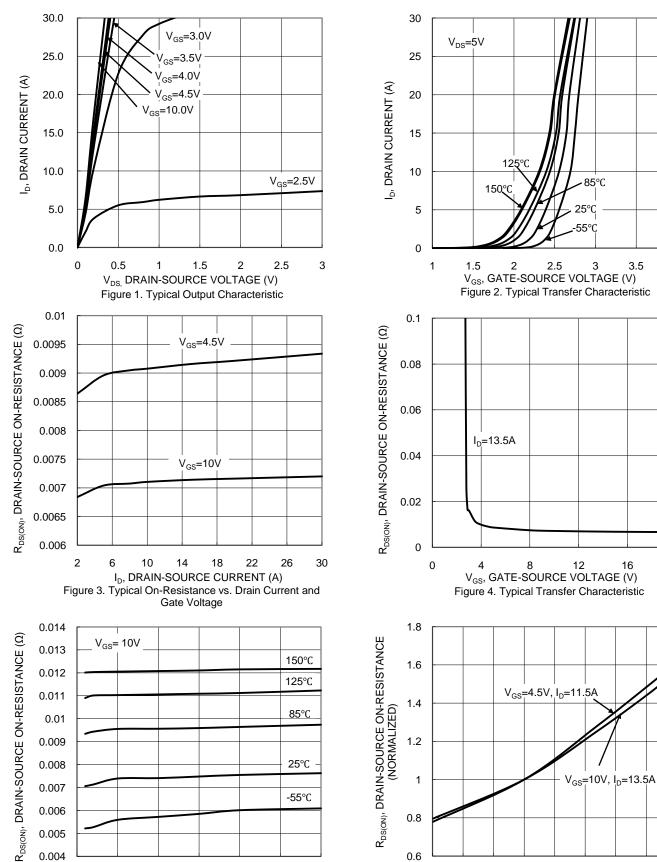
<sup>6.</sup> Device mounted on infinite heat sink and measured by thermal couple attached on bottom heat sink of package.

<sup>7.</sup> Short duration pulse test used to minimize self-heating effect.

<sup>8.</sup> Guaranteed by design. Not subject to product testing.

20





I<sub>D</sub>, DRAIN CURRENT (A) Figure 5. Typical On-Resistance vs. Drain Current and Junction Temperature

15

20

25

10

Figure 6. On-Resistance Variation with Junction Temperature December 2015

75

100 125

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50

T<sub>J</sub>, JUNCTION TEMPERATURE (°C)

0

0.005 0.004

30

0.6

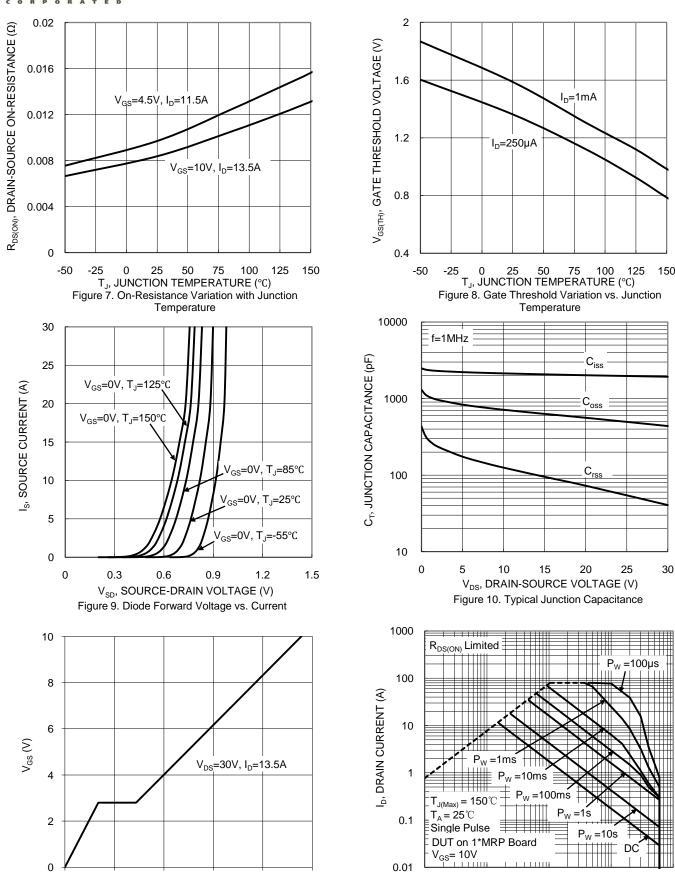
-50

-25

0

25





0

7

21

 $Q_g(nC)$ 

Figure 11. Gate Charge

0.01

35

28

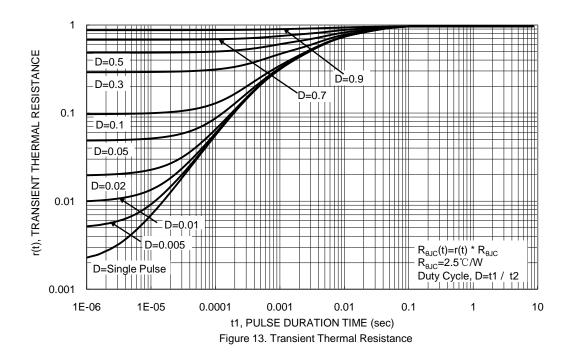
10

V<sub>DS</sub>, DRAIN-SOURCE VOLTAGE (V)

Figure 12. SOA, Safe Operation Area

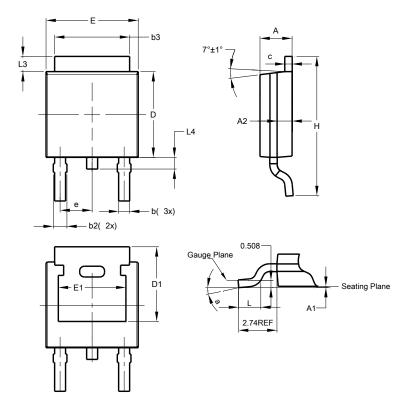
100





## **Package Outline Dimensions**

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.

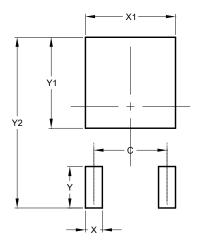


TO252 (DPAK)					
Dim	Min	Max	Тур		
Α	2.19	2.39	2.29		
A1	0.00	0.13	0.08		
A2	0.97	1.17	1.07		
b	0.64	0.88	0.783		
b2	0.76	1.14	0.95		
b3	5.21	5.46	5.33		
С	0.45	0.58	0.531		
D	6.00	6.20	6.10		
D1	5.21	-	-		
е	-	-	2.286		
Е	6.45	6.70	6.58		
E1	4.32	-	-		
H	9.40	10.41	9.91		
Г	1.40	1.78	1.59		
L3	0.88	1.27	1.08		
L4	0.64	1.02	0.83		
а	0°	10°	-		
All Dimensions in mm					



### Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
С	4.572
Х	1.060
X1	5.632
Υ	2.600
Y1	5.700
Y2	10.700

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